



## JST138F-800E 12A TRIAC

Rev.A.1.0

The JST138F-800E triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. By using an external plastic package, JST138F-800E provides a rated insulation voltage of 2000 VRMS, complying with UL standards (File ref: E252906). Package TO-220F is RoHS compliant.

Parameter	Symbol	Value	Unit
Storage junction temperature range	T <sub>stg</sub>	-40-150	
Operating junction temperature range	T <sub>j</sub>	-40-125	

Repetitive peak off-state voltage (T<sub>j</sub>=26 (v)15.8 9e 0 128<9am -8 (65)T<sub>j</sub> EMC /P <>/MCID 18 >>18

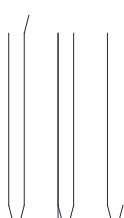
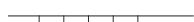
Peak pulse voltage (T <sub>j</sub> =25 ; non-repetitive,off-state;FIG.7)	V <sub>pp</sub>	3.5	kV
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(T<sub>j</sub>=25 unless otherwise specified)

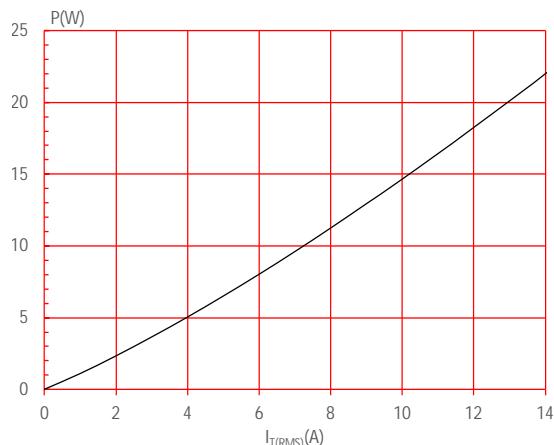
Symbol	Test Condition	Quadrant	Value		Unit
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33	- -	MAX.	10	mA
				25	
V <sub>GT</sub>		ALL	MAX.	1	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125 R <sub>L</sub> =3.3K	ALL	MIN.	0.2	V
I <sub>L</sub>	I <sub>G</sub> =1.2I <sub>GT</sub>	- -	MAX.	25	mA
				35	
I <sub>H</sub>	I <sub>T</sub> =500mA		MAX.	25	mA
dV/dt	V <sub>D</sub> =540V Gate Open T <sub>j</sub> =125		MIN.	100	V/s
(dV/dt)c	(dI/dt)c=5A/ms, T <sub>j</sub> =110		MIN.	5	
t <sub>on</sub>	I <sub>G</sub> =40mA I <sub>A</sub> =200mA I <sub>R</sub> =20mA T <sub>j</sub> =25	TYP.	3	s	
t <sub>off</sub>			30		

Symbol	Parameter	Value(MAX.)	Unit
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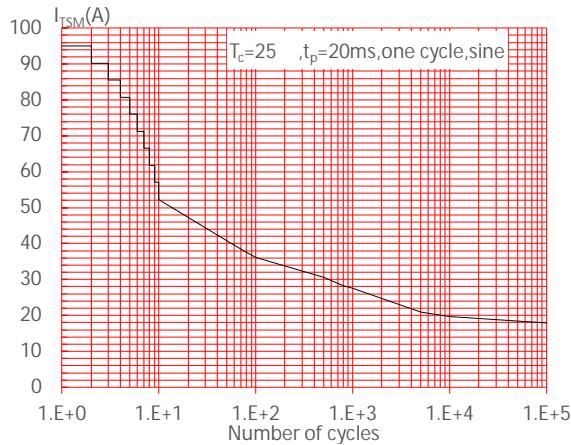
J	ST	138	F	-800	E
JieJie Microelectronics Co., Ltd.					
	Triacs				
		I <sub>T(RMS)</sub> :12A			
			F:TO-220F(Ins)		
				800:V <sub>DRM</sub> /V <sub>RRM</sub> 800V	
				E:IGT1-3 10mA IGT4 25mA	



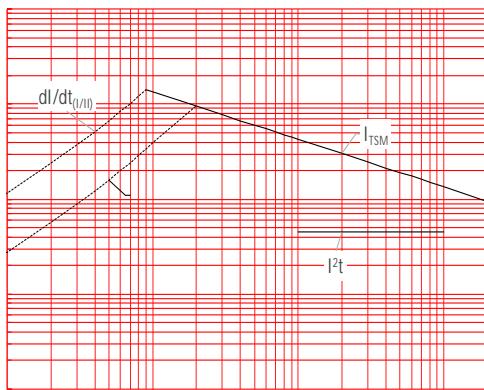
**FIG.1** Maximum power dissipation versus RMS on-state current



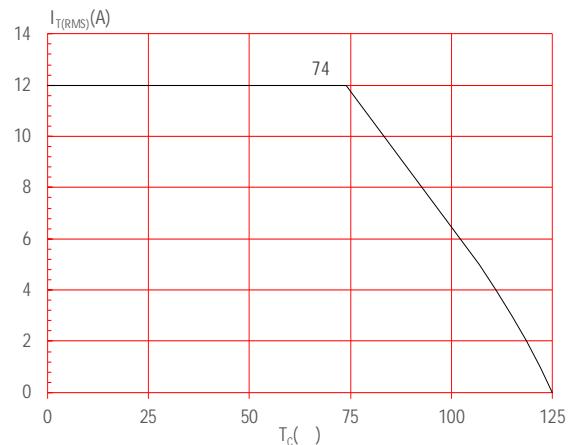
**FIG.3:** Surge peak on-state current versus number of cycles



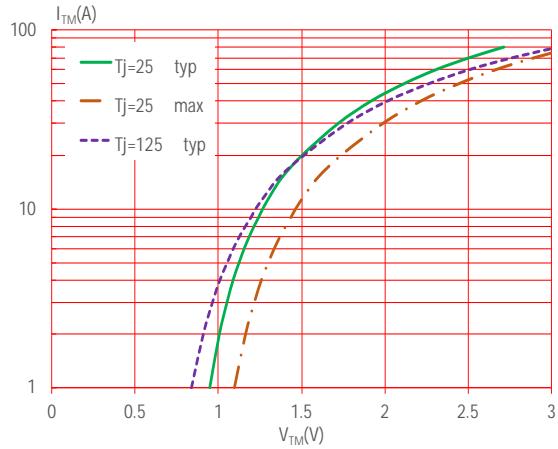
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( - :  $dI/dt < 80$   
- :  $dI/dt < 50$  )



**FIG.2:** RMS on-state current versus case temperature

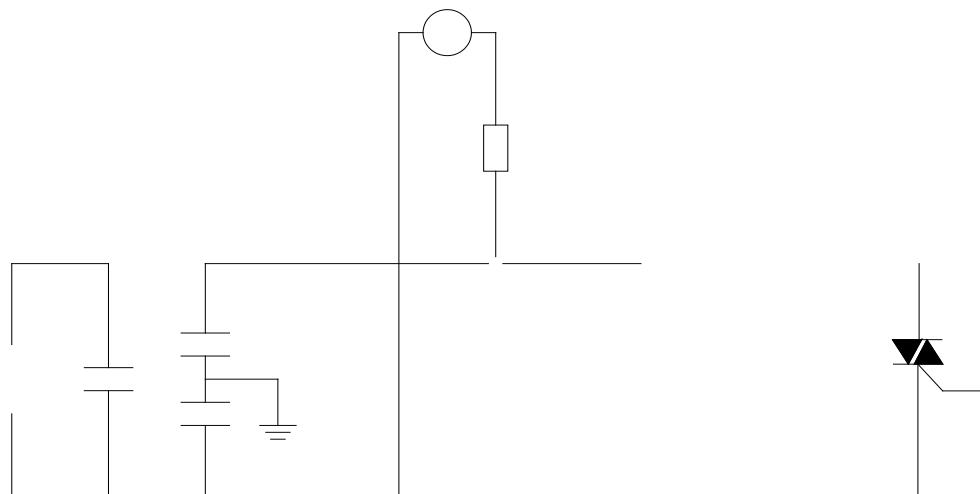


**FIG.4:** On-state character



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

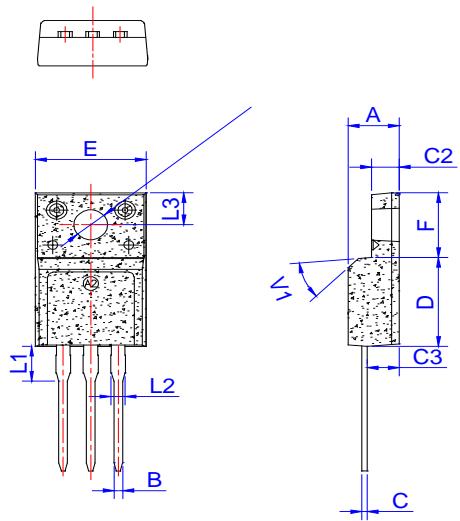
FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		-	-			
<b>JST138F-800E</b>	<b>800</b>	<b>10</b>	<b>25</b>	<b>TO-220F(Ins)</b>	<b>50</b>	<b>Tube</b>

### Document Revision History

Date	Revision	Changes
Apr.14, 2023	A.1.0	Last updated



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